# NSN 5961-00-839-3944

Transistor - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.650 inches

## **Overall Diameter:**

0.850 inches

# Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

### Features Provided:

Hermetically sealed case

Thread Size:

0.250 inches

### Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 28.0

breakdown voltage, emitter-to-base, collector open

### **Current Rating Per Characteristic:**

Between 1.50 amperes source cutoff current and 12.00 amperes source cutoff current

### Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnp

### **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

4 tab, solder lug

#### Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

# Fiig:

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